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UF4001 ~ UF4007

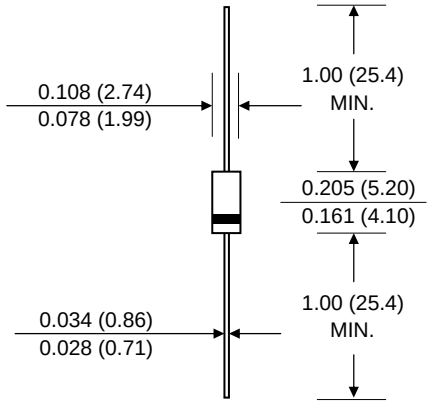
ULTRA FAST EFFICIENT RECTIFIER DIODES

PRV : 50 ~ 1000 Volts
Io : 1.0 Ampere

FEATURES :
* High current capability
* High surge current capability
* High reliability
* Low reverse current
* Low forward voltage drop
* Fast switching for high efficiency
* Pb / RoHS Free

MECHANICAL DATA :
* Case : DO-41 Molded plastic
* Epoxy : UL94V-O rate flame retardant
* Lead : Axial lead solderable per MIL-STD-202, Method 208 guaranteed
* Polarity : Color band denotes cathode end
* Mounting position : Any
* Weight : 0.34 gram

DO - 41



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

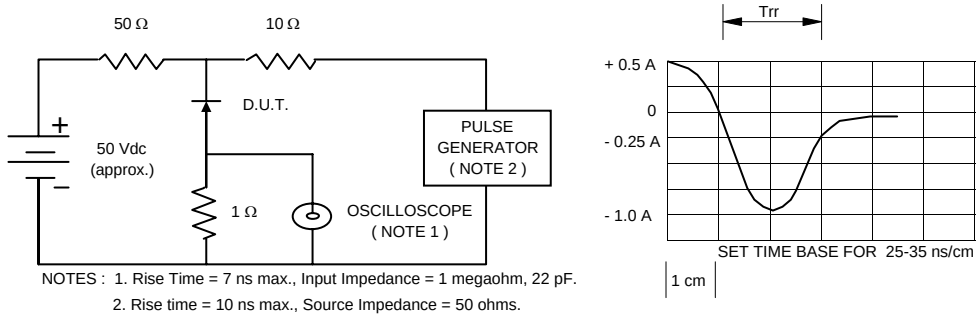
Rating at 25 °C ambient temperature unless otherwise specifie.
Single phase, half wave, 60 Hz, resistive or inductive load
For capacitive load, derate current by 20%

RATING	SYMBOL	UF 4001	UF 4002	UF 4003	UF 4004	UF 4005	UF 4006	UF 4007	UNIT
Maximum Recurrent Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Current 0.375"(9.5mm) Lead Length Ta = 55 °C	$I_{F(AV)}$	1.0							A
Maximum Peak Forward Surge Current, 8.3ms Single half sine wave superimposed on rated load (JEDEC Method)	I_{FSM}	30							A
Maximum Forward Voltage at I_F = 1.0 A	V_F	1.0				1.7			V
Maximum DC Reverse Current Ta = 25 °C	I_R	10							µA
at Rated DC Blocking Voltage Ta = 100 °C	$I_{R(H)}$	50							µA
Maximum Reverse Recovery Time (1)	Trr	50				75			ns
Typical Junction Capacitance (2)	C_J	17							pf
Typical Thermal Resistance (3)	RθJA	60							°C/W
Junction Temperature Range	T_J	- 65 to + 150							°C
Storage Temperature Range	T_{STG}	- 65 to + 150							°C

Notes : (1) Reverse Recovery Test Conditions : I_F = 0.5 A, I_R = 1.0 A, Irr = 0.25 A.
(2) Measured at 1.0 MHz and applied reverse voltage of 4.0 V_{DC}
(3) Thermal Resistance from Junction to Ambient, 0.375" , 9.5 mm Lead Lengths.

RATING AND CHARACTERISTIC CURVES (UF4001 ~ UF4007)

FIG.1 - REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM



NOTES : 1. Rise Time = 7 ns max., Input Impedance = 1 megaohm, 22 pF.
2. Rise time = 10 ns max., Source Impedance = 50 ohms.
3. All Resistors = Non-inductive Types.

FIG.2 - DERATING CURVE FOR OUTPUT RECTIFIED CURRENT

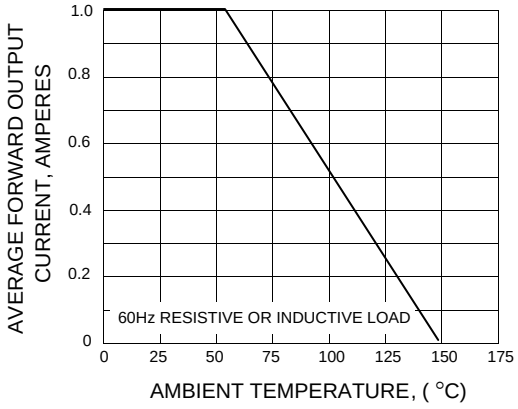


FIG.3 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

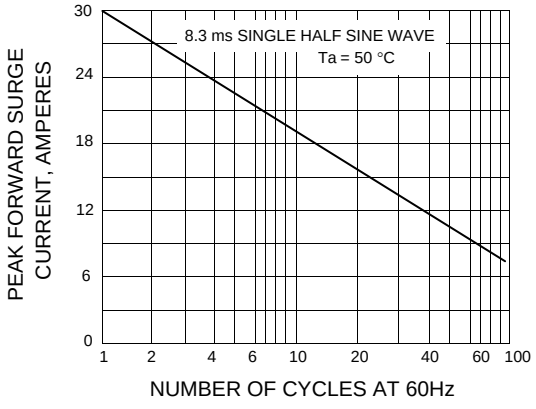


FIG.4 - TYPICAL FORWARD CHARACTERISTICS

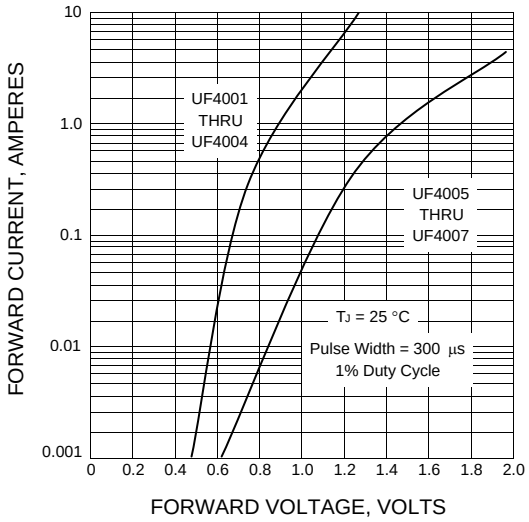


FIG.5 - TYPICAL REVERSE CHARACTERISTICS

